

ELECTRON TRANSPORT IN MOLECULAR NANOSTRUCTURES

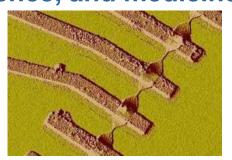
Nanoscale Science and Engineering Center, Columbia University - Grant Number CHE-0641523 James T. Yardley, Managing Director; Tony Heinz and Ronald Breslow, Scientific Directors

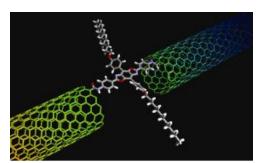




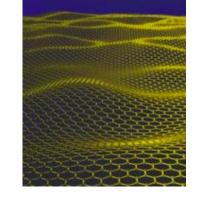
COLUMBIA NANOCENTER OVERVIEW

The Center for Electron Transport in Molecular Nanostructure at Columbia University seeks to establish the foundation for new paradigms for information processing through the development of fundamental understanding of charge transport phenomena unique to the character of nanoscale molecular structures. Beyond electronics applications, the fundamental studies of molecular transport in the Columbia Nanocenter have the potential to impact other disciplines such as photonics, biology, neuroscience, and medicine.









Basic questions addressed by the Center's research program include:

- What are the fundamental principles that determine the response of a molecular system to application of electric potentials?
- Under what circumstances is the conductance of a molecule quantized?
- What are the design rules governing charge transport phenomena in molecular nanostructures?
- How do we contact molecular systems with metallic electrodes?
- What is the nature of the contact to individual molecular systems?
- How do we design components for molecular circuitry?
- What are the mechanisms for modulation of the conductance of a molecule?
- How can we build molecules containing the operational functions of a transistor?

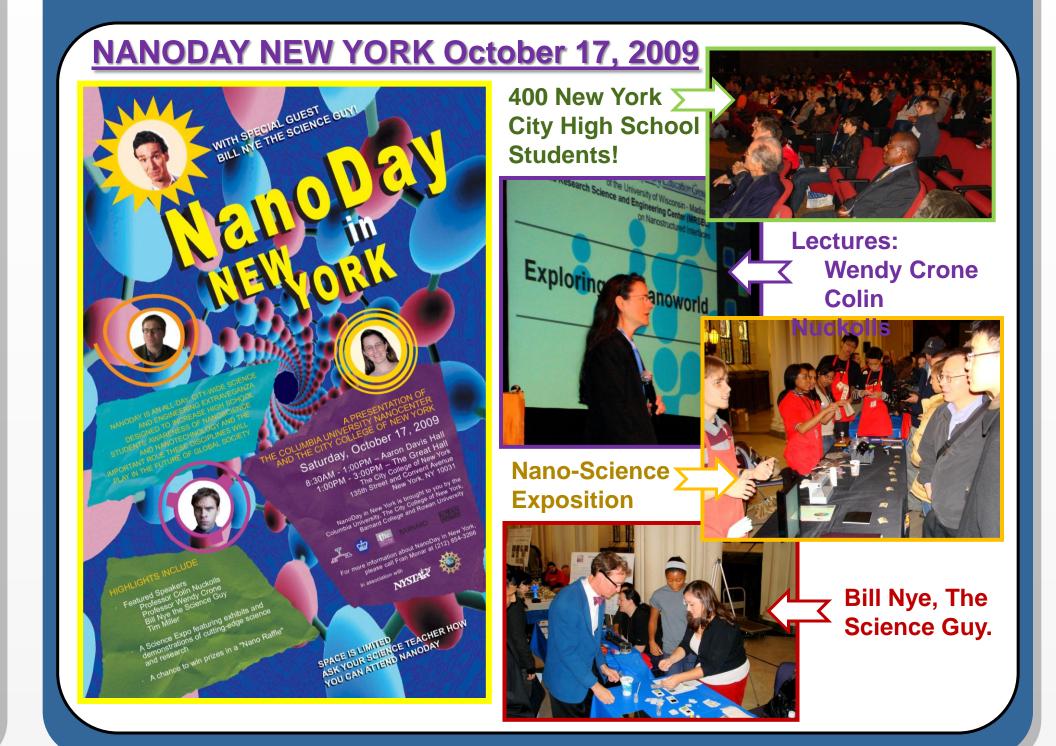
COLUMBIA NANOCENTER STRUCTURE

- 16 Principal Investigators from 6 different departments: Chemistry, Physics, Applied Physics, Electrical Engineering, Chemical Engineering and Mechanical Engineering.
- Academic affiliates: Barnard College, City College, Rowan University.
- Industrial affiliates: Alcatel/Lucent, DuPont, IBM, Intel, SRC/SIA
- Government Laboratory Partners: Brookhaven National Lab, Molecular Foundry (LBL), Network for Computational Nanotechnology, SRC (NRI).
- Encompasses approximately 75 researchers, including graduate students and postdocs.

Research Thrust Areas:

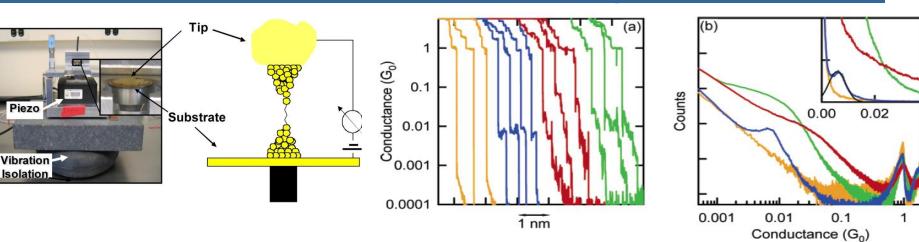
- Electron transport and basic physics of graphene and molecular films.
- Electron transport in carbon nanotubes.
- Electron transport in single molecules.
- Non-equilibrium quantum coherent devices in 1-D materials (NRI).

EDUCATION and OUTREACH



TRANSPORT in SINGLE MOLECULES

Defined Molecular Conductance in Organic Molecules.



STM-based conductance measurements. (a) Sample conductance traces measured without molecules (yellow) and with 1,4-benzenediamine (blue), 1,4-benzenedithiol (red), and 1,4-benzenediisonitrile (green) shown on a semilog plot. (All data were measured at 25 mV bias, although no bias dependence was found up to 250 mV.) (b) Conductance histograms constructed from over 3000 traces measured in the presence of 1,4-benzenediamine (blue), 1,4-benzenedithiol (red), and 1,4-benzenediisonitrile (green) shown on a log-log plot. The control histogram of Au without molecules is also shown (yellow). Histograms are normalized by the number of traces used to construct the histograms. Inset: same data on a linear plot showing a Gaussian fit to the peak (black curve). Bin size is 10^{-4} G₀.

Mark S. Hybertsen, Latha Venkataraman, Jennifer E. Klare, Adam C. Whalley, Michael L. Steigerwald, and Colin Nuckolls. "Amine-Linked Single-Molecule Circuits: Systematic Trends Across Molecular Families." J. Phys.: Condens. Matter 20, 374115 (2008).

One molecule with two conducting states!

Measurement of Molecular Transport in Bipyridine Systems.

0.0 0.4

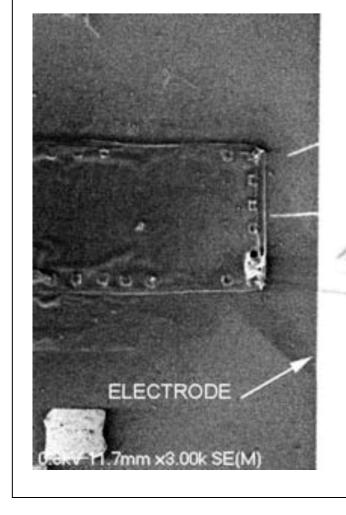
0.0 0.2 0.4 0.6

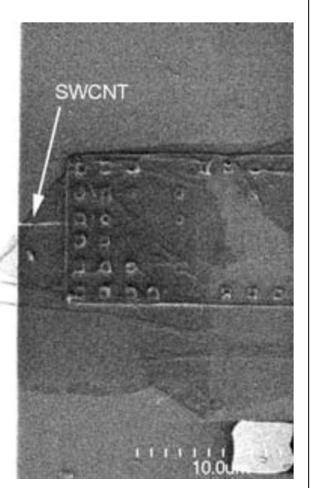
well coupled to the π -system resulting in lower conductance.

CARBON NANOTUBES AND DEVICES

Translocation of DNA Through Single Walled Carbon Nanotubes..

Electron micrograph showing microfluidic chambers with interconnecting carbon nanotube and flow control electrode. Device is fabricated with PDMS, a polymeric material.





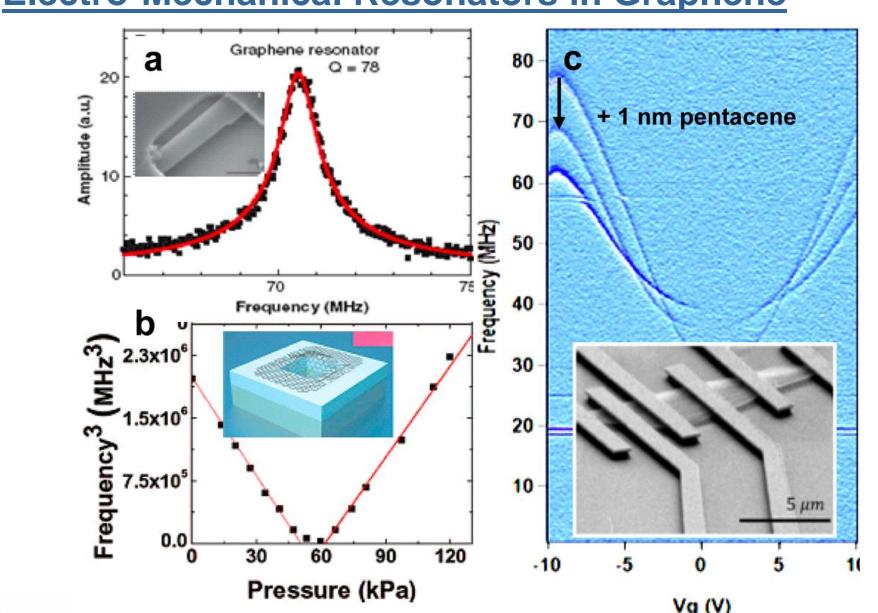
In the group of Colin Nuckolls with additional collaboration with Prof Stuart Lindsay at Arizona, the Nanocenter has reported for the first time the use of single-walled carbon nanotubes (SWCNTs) as nanopores for analyzing molecular transport properties. Nanopores are orifices of molecular diameter that connect two fluid reservoirs. At this length scale, the passage of even a single molecule generates a detectable change in the flow of ionic current through the pore. In particular, the group has fabricated microfluidic devices in which one single-walled carbon nanotube spans a barrier between two fluid reservoirs, enabling direct electrical measurement of ion transport through the tube. Relative to CNT membranes, this arrangement makes it possible to detect signals from the translocation of a single molecule and to correlate transport with the properties of individual

Impact: Carbon nanotubes simplify the construction of nanopores, permit new types of electrical measurements, and may open avenues for control of DNA translocation. Such devices may be used as single-molecule Coulter counters and form the basis of proposed new approaches to DNA sequencing.

Reference: Haitao Liu, Jin He, Jinyao Tang, Hao Liu, Pei Pang, Di Cao, Predrag Krstic, Sony Joseph, Stuart Lindsay and Colin Nuckolls. "Translocation of Single-Stranded DNA Through Single-Walled Carbon Nanotubes". Science (Washington, DC, U. S.) 327, 64-67 (2010).

GRAPHENE: A NEW ELECTRONIC MATERIAL

Electro-Mechanical Resonators in Graphene



Recent studies have shown that graphene membranes can act as NEMS resonators in the megahertz range. Electrical readout of these devices is important for integration, and is attractive for many applications. In addition, characterization of the basic attributes of these devices, including their response to applied voltage, added mass and changes in temperature, allows detailed modelling of their behavior. These new resonators are voltage tunable and offer detection of mass to very low levels.

Stormer, Tony F. Heinz and James Hone. "Performance of monolayer graphene nanomechanical resonators with electrical readout". Nat. Nanotechnol. 4, 861-867 (2009).

Reference: Changyao Chen, Sami Rosenblatt, Kirill I. Bolotin, William Kalb, Philip Kim, Ioannis Kymissis, Horst L.

Single Molecule Transistors for Bio-Medical Sensing.

Venkataraman. "Conductance and Geometry of Pyridine-Linked Single-Molecule Junctions". J. Am. Chem. Soc. 132, 6817-6821 (2010)

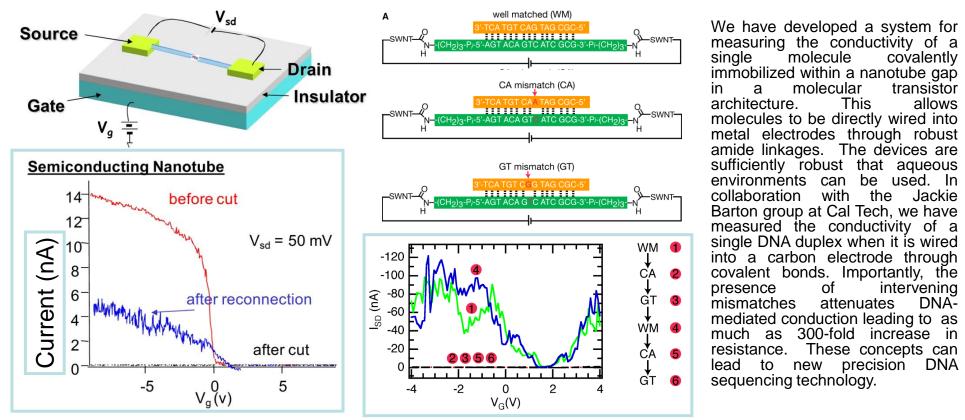
In our STM-based conductance measurements we directly measure conductance as a function of displacement. By building histograms of this data for many measurements, we establish the overall distribution of molecular

conductances as a function of displacement. The data strongly support the hypothesis that at short distances a

junction forms with C-N-Au angle smaller than 180°. Thus the Au is better coupled to the molecular π -system

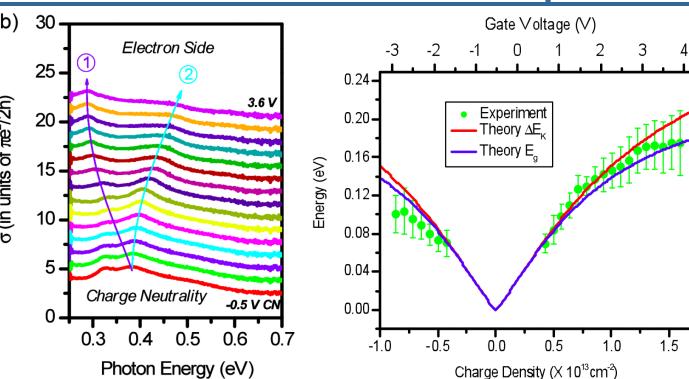
giving higher conductance. On pulling, the molecule becomes vertical in the junction. In this state the Au is not

M. Kamenetska, Su Ying Quek, A. C. Whalley, M. L. Steigerwald, H. J. Choi, Steven G. Louie, C. Nuckolls, M. S. Hybertsen, J. B. Neaton and L.



Xuefeng Guo, Alon A. Gorodetsky, James Hone, Jacqueline K. Barton and Colin Nuckolls. "Conductivity of a single DNA duplex bridging a carbon nanotube gap". Nature Nanotechnology 3, 163-167 (2008); Xuefeng Guo and Colin Nuckolls. "Functional single-molecule devices based on SWNTs as point contacts". J. Mater. Chem. 19, 5470-5473 (2009).

Electric Field Induced Band-Gap in Bilayer Graphene



Bilayer graphene is an attractive two dimensional (2D) physics, as well as for many potential device applications. In the bilayer system, the band structure arises from the coupling of two graphene monolayers. This bilayer system shares many of the interesting properties of graphene, but provides a richer band structure. Theoretical studies have predicted that a significant band gap could be induced through the application of a perpendicular electric field, producing a material with an electrically tunable band gap, a phenomenon of great significance for both basic physics and applications. We have observed direct spectroscopic signatures of the opening of a large and tunable band gap in bilayer graphene induced by a

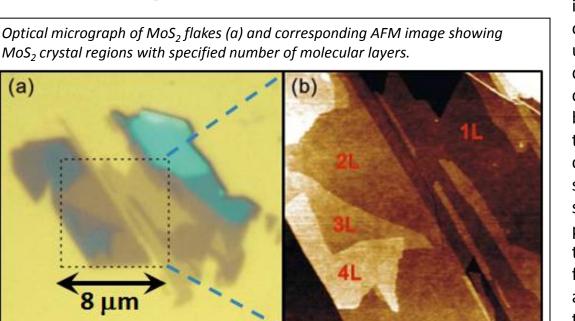
perpendicular electric field.

solid st

Reference: Kin Fai Mak, Chun Hung Lui, Jie Shan and Tony F. Heinz. "Observation of an Electric-Field-Induced Band Gap in Bilayer Graphene by Infrared Spectroscopy". Phys. Rev. Lett. 102, 256405/256401-256405/256404 (2009).

Reference: Kin Fai Mak, Changgu Lee, James Hone, Jie Shan and Tony F. Heinz. "Atomi gap semiconductor". Phys. Rev. Lett. (2010).

Single Molecular Sheet of Molybdenum Sulfide: A New



Direct-Gap Semiconductor

The material MoS₂ has attracted great interest because of its distinctive electronic, optical, and catalytic properties. We report ultrathin crystals of MoS₂, with thicknesses down to a single molecular monolayer, corresponding to just half a unit cell of the bulk crystal (c = 6.14 Å). With decreasing thickness the MoS₂ crystals exhibit dramatic changes in their electronic structure. Further spectroscopic measurements reveal a systematic change in the electronic properties of the material with crystal thickness and the existence of a crossover from the dark indirect-gap semiconductor to a luminescent direct-gap semiconductor in the limit of single MoS₂ monolayer.

The crossover from an indirect to direct band-gap material arises from a strong confinement-induced increase for the material's indirect band gap. These new nanoscale materials may find exciting new applications in electronic devices, in solid state lighting, or in new mechanical structures

Reference: Kin Fai Mak, Changgu Lee, James Hone, Jie Shan and Tony F. Heinz. "Atomically thin MoS_2 : a new directapp semiconductor". Phys. Rev. Lett. (2010).

NANOELECTRONICS RESEARCH INITIATIVE*

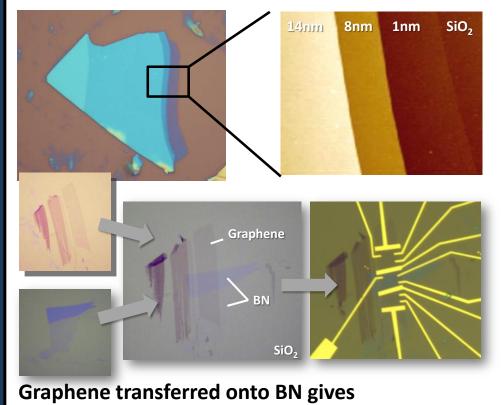
anoelectronics

The Columbia Nanocenter is a recipient of a supplemental award from NSF and from the Semiconductor Industry's Nanoelectronics Research Initiative (NRI) to explore "Non-equilibrium Quantum Coherent Devices in 1-D Materials" as a concept for information processing beyond CMOS silicon.

Graphene: Basis for New Semiconductor Devices

Graphene exhibits extremely high mobilities and offers flexibility to create many new functional electronic devices. However on SiO₂ and other conventional

flexibility to create many new functional electronic devices. However on SiO₂ and other conventional substrates the mobility is substantially reduced due to electron-phonon scattering. Boron Nitride has high energy phonons which couple weakly to electrons and thus offers the possibility for enhanced mobility.



>60,000 cm²/V sec mobility at room temperature!

We have fabricated graphene devices on BN substrates that exhibit mobilities almost an order of magnitude better than the corresponding devices on SiO₂. These devices also show reduced roughness, intrinsic doping and chemical reactivity. The ability to assemble crystalline layered materials in a controlled way permits the fabrication of graphene devices on other promising dielectrics and allows for the realization of

more complex graphene heterostructures.

Reference: C. R. Dean, A. F. Young, I. Meric, C. Lee, L. Wang, S.
Sorgenfrei, K. Watanabe, T. Taniguchi, P. Kim, K. L. Shepard and J. Hone.
"Boron nitride substrates for high quality graphene electronics". Nature

Nanotech. 5, 722-726 (2010).

*This program is supported by the NSF and the

SRC via the Nanoelectronics Research Initiative".

Support for this work was provided by the Nanoscale Science and Engineering Center program of the NSF under Grants No. CHE-0117752 and CHE-0641523 and by the New York State Office of Science, Technology, and Academic Research (NYSTAR).